

# DATA SHEET

For a complete data sheet, please also download:

- The IC06 74HC/HCT/HCU/HCMOS Logic Family Specifications

## **74HC/HCT4066** Quad bilateral switches

Product specification  
Supersedes data of 1998 Oct 02  
File under Integrated Circuits, IC06

1998 Nov 10

## Quad bilateral switches

## 74HC/HCT4066

## FEATURES

- Very low “ON” resistance:  
50  $\Omega$  (typ.) at  $V_{CC} = 4.5$  V  
45  $\Omega$  (typ.) at  $V_{CC} = 6.0$  V  
35  $\Omega$  (typ.) at  $V_{CC} = 9.0$  V
- Output capability: non-standard
- $I_{CC}$  category: SSI.

The 74HC/HCT4066 have four independent analog switches. Each switch has two input/output terminals (nY, nZ) and an active HIGH enable input (nE). When nE is LOW the belonging analog switch is turned off.

The “4066” is pin compatible with the “4016” but exhibits a much lower “ON” resistance. In addition, the “ON” resistance is relatively constant over the full input signal range.

## GENERAL DESCRIPTION

The 74HC/HCT4066 are high-speed Si-gate CMOS devices and are pin compatible with the “4066” of the “4000B” series. They are specified in compliance with JEDEC standard no. 7A.

## QUICK REFERENCE DATA

GND = 0 V;  $T_{amb} = 25$  °C;  $t_r = t_f = 6$  ns

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
$t_{PZH}/t_{PZL}$	turn-on time nE to $V_{OS}$	$C_L = 15$ pF; $R_L = 1$ k $\Omega$ ; $V_{CC} = 5$ V	11	12	ns
$t_{PHZ}/t_{PLZ}$	turn-off time nE to $V_{OS}$		13	16	ns
$C_I$	input capacitance		3.5	3.5	pF
$C_{PD}$	power dissipation capacitance per switch	notes 1 and 2	11	12	pF
$C_S$	max. switch capacitance		8	8	pF

## Notes

1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W):
  - a)  $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{(C_L + C_S) \times V_{CC}^2 \times f_o\}$  where:
    - b)  $f_i$  = input frequency in MHz
    - c)  $f_o$  = output frequency in MHz
    - d)  $\sum \{(C_L + C_S) \times V_{CC}^2 \times f_o\}$  = sum of outputs
    - e)  $C_L$  = output load capacitance in pF
    - f)  $C_S$  = maximum switch capacitance in pF
    - g)  $V_{CC}$  = supply voltage in V
2. For HC the condition is  $V_I = \text{GND to } V_{CC}$   
For HCT the condition is  $V_I = \text{GND to } V_{CC} - 1.5$  V

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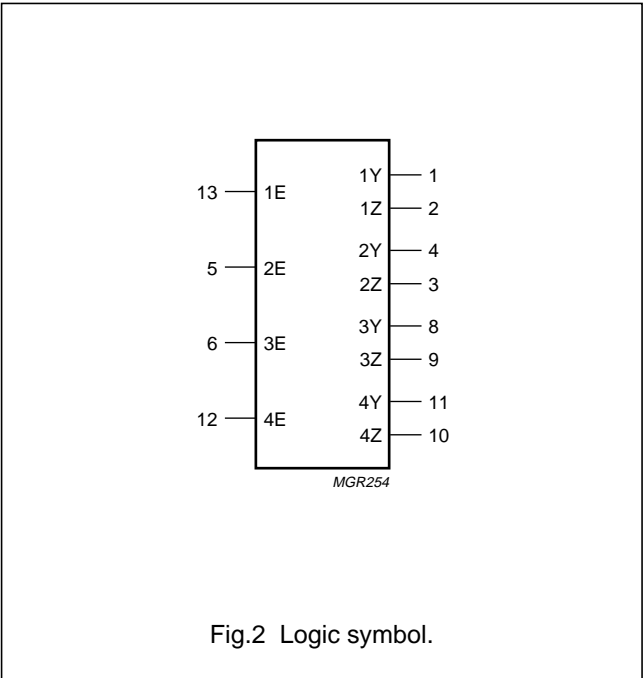
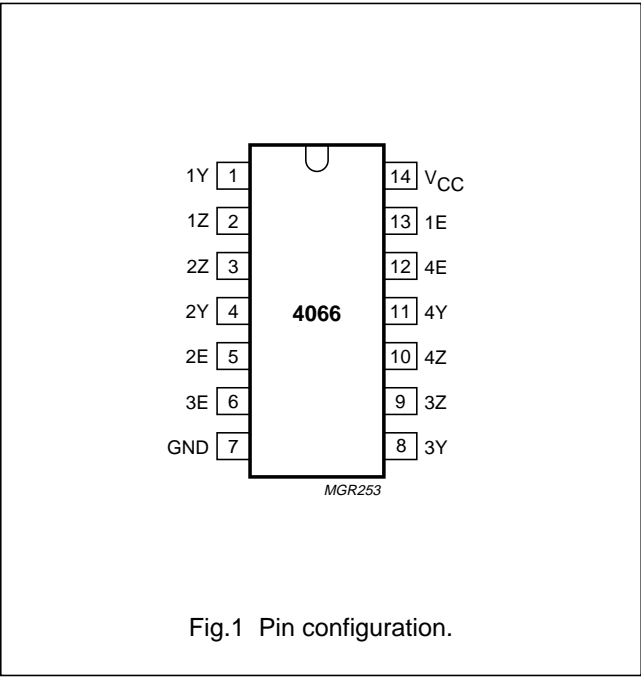
74HC/HCT4066

ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
74HC4066	DIP14	plastic dual in-line package; 14 leads (300 mil)	SOT27-1
74HC4066	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1
74HC4066	SSOP14	plastic shrink small outline package; 14 leads; body width 5.3 mm	SOT337-1
74HC4066	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1
74HCT4066	DIP14	plastic dual in-line package; 14 leads (300 mil)	SOT27-1
74HCT4066	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1
74HCT4066	SSOP14	plastic shrink small outline package; 14 leads; body width 5.3 mm	SOT337-1
74HCT4066	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1

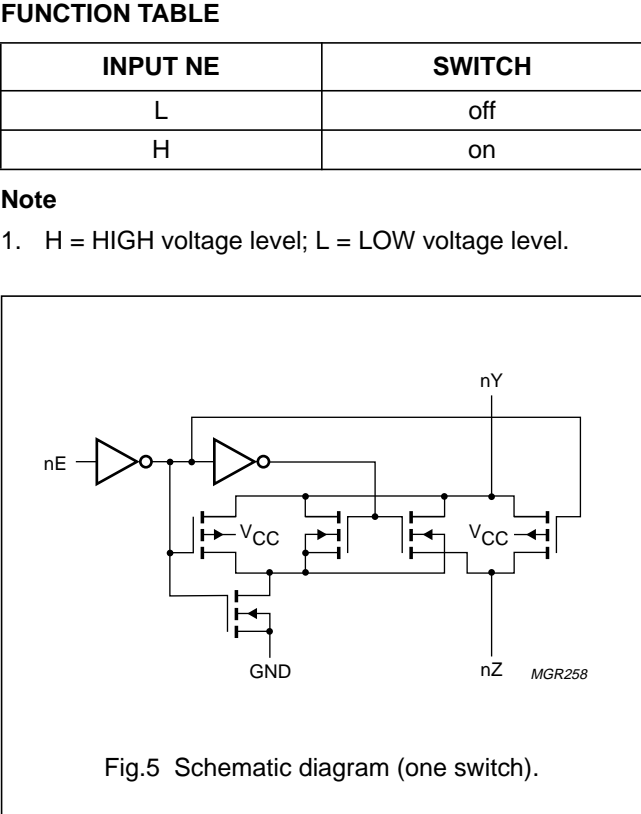
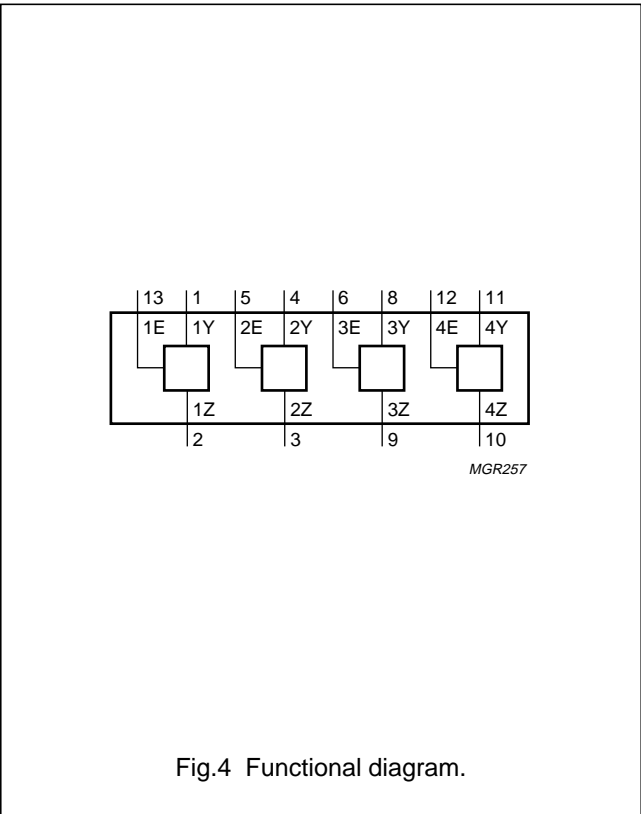
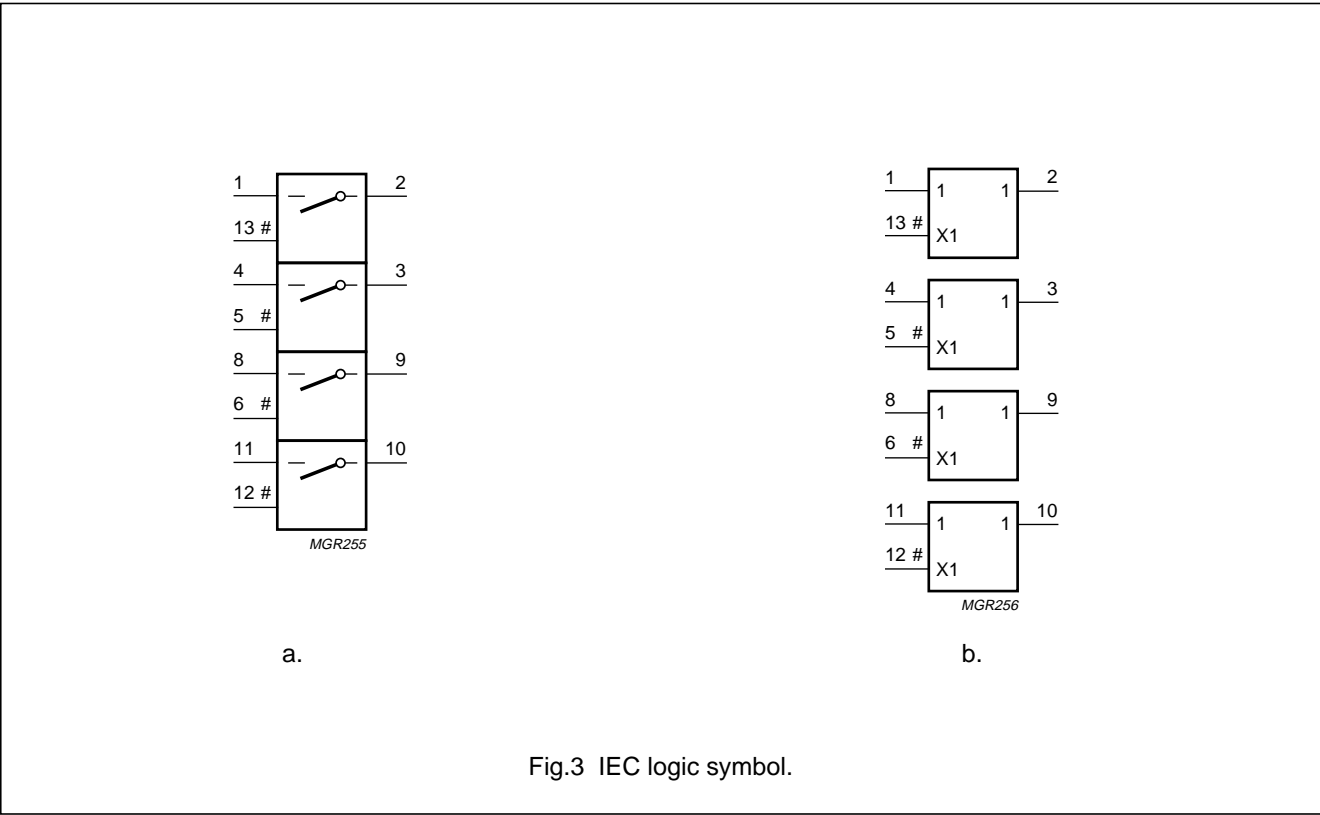
PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1, 4, 8, 11	1Y to 4Y	independent inputs/outputs
2, 3, 9, 10	1Z to 4Z	independent inputs/outputs
7	GND	ground (0 V)
13, 5, 6, 12	1E to 4E	enable inputs (active HIGH)
14	V <sub>CC</sub>	positive supply voltage



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## RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134) Voltages are referenced to GND (GND = 0 V)

SYMBOL	PARAMETER	MIN.	MAX.	UNIT	CONDITIONS
$V_{CC}$	DC supply voltage	-0.5	+11.0	V	
$\pm I_{IK}$	DC digital input diode current		20	mA	for $V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V
$\pm I_{SK}$	DC switch diode current		20	mA	for $V_S < -0.5$ V or $V_S > V_{CC} + 0.5$ V
$\pm I_S$	DC switch current		25	mA	for $-0.5$ V $< V_S < V_{CC} + 0.5$ V
$\pm I_{CC};$ $\pm I_{GND}$	DC $V_{CC}$ or GND current		50	mA	
$T_{stg}$	storage temperature range	-65	+150	°C	
$P_{tot}$	power dissipation per package  plastic DIL plastic mini-pack (SO)		750 500	mW mW	for temperature range: -40 to +125 °C 74HC/HCT above +70 °C: derate linearly with 12 mW/K above +70 °C: derate linearly with 8 mW/K
$P_S$	power dissipation per switch		100	mW	

## Note

1. To avoid drawing  $V_{CC}$  current out of terminal nZ, when switch current flows in terminal nY, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no  $V_{CC}$  current will flow out of terminal nY. In this case there is no limit for the voltage drop across the switch, but the voltages at nY and nZ may not exceed  $V_{CC}$  or GND.

## RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	74HC			74HCT			UNIT	CONDITIONS
		min.	typ.	max.	min.	typ.	max.		
$V_{CC}$	DC supply voltage	2.0	5.0	10.0	4.5	5.0	5.5	V	
$V_I$	DC input voltage range	GND		$V_{CC}$	GND		$V_{CC}$	V	
$V_S$	DC switch voltage range	GND		$V_{CC}$	GND		$V_{CC}$	V	
$T_{amb}$	operating ambient temperature range	-40		+85	-40		+85	°C	see DC and AC CHARACTERISTICS
$T_{amb}$	operating ambient temperature range	-40		+125	-40		+125	°C	
$t_r, t_f$	input rise and fall times		6.0	1000 500 400 250		6.0	500	ns	$V_{CC} = 2.0$ V $V_{CC} = 4.5$ V $V_{CC} = 6.0$ V $V_{CC} = 10.0$ V

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## DC CHARACTERISTICS FOR 74HC/HCT

For 74HC:  $V_{CC} = 2.0, 4.5, 6.0$  and  $9.0$  V; For 74HCT:  $V_{CC} = 4.5$  V

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)							UNIT	TEST CONDITIONS			
		74HC/HCT								V <sub>CC</sub> (V)	I <sub>S</sub> (μA)	V <sub>IS</sub>	V <sub>I</sub>
		+25			−40 to +85		−40 to +125						
		min.	typ.	max.	min.	max.	min.	max.					
R <sub>ON</sub>	ON-resistance (peak)		—	—		—		—	Ω	2.0	100	V <sub>CC</sub> to GND	V <sub>IH</sub> or V <sub>IL</sub>
			54	95		118		142	Ω	4.5	1000		
			42	84		105		126	Ω	6.0	1000		
			32	70		88		105	Ω	9.0	1000		
R <sub>ON</sub>	ON-resistance (rail)		80	—		—		—	Ω	2.0	100	GND	V <sub>IH</sub> or V <sub>IL</sub>
			35	75		95		115	Ω	4.5	1000		
			27	65		82		100	Ω	6.0	1000		
			20	55		70		85	Ω	9.0	1000		
R <sub>ON</sub>	ON-resistance (rail)		100	—		—		—	Ω	2.0	100	V <sub>CC</sub>	V <sub>IH</sub> or V <sub>IL</sub>
			42	80		106		128	Ω	4.5	1000		
			35	75		94		113	Ω	6.0	1000		
			27	60		78		95	Ω	9.0	1000		
ΔR <sub>ON</sub>	maximum variation of ON-resistance between any two channels		—						Ω	2.0		V <sub>CC</sub> to GND	V <sub>IH</sub> or V <sub>IL</sub>
			5						Ω	4.5			
			4						Ω	6.0			
			3						Ω	9.0			

## Note

- At supply voltages approaching 2 V, the analog switch ON-resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.

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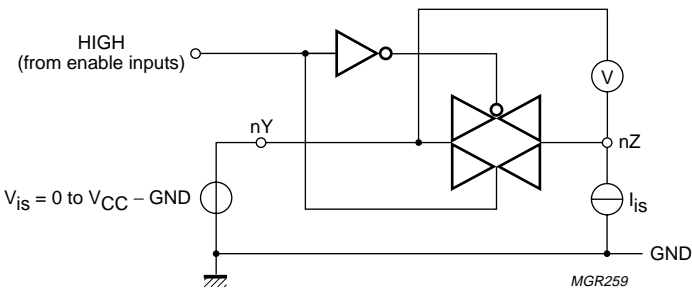


Fig.6 Test circuit for measuring ON-resistance ( $R_{ON}$ ).

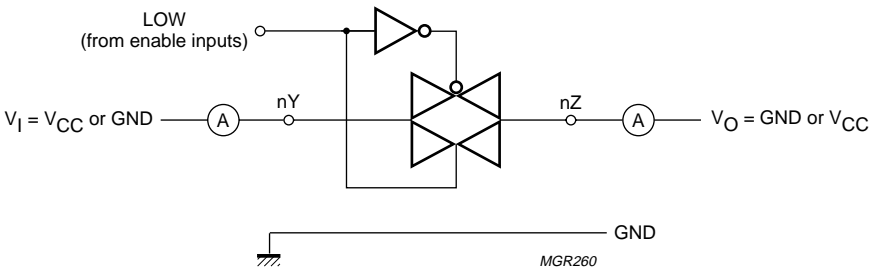


Fig.7 Test circuit for measuring OFF-state current.

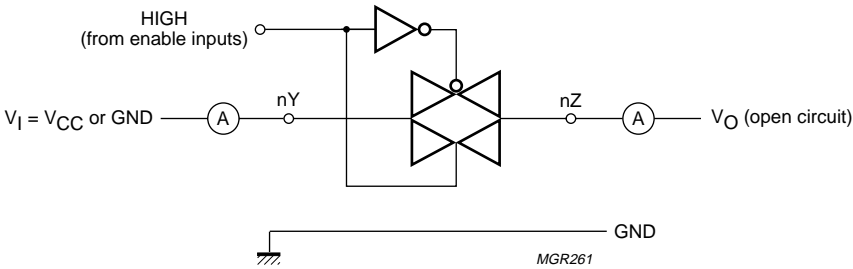


Fig.8 Test circuit for measuring ON-state current.

Quad bilateral switches

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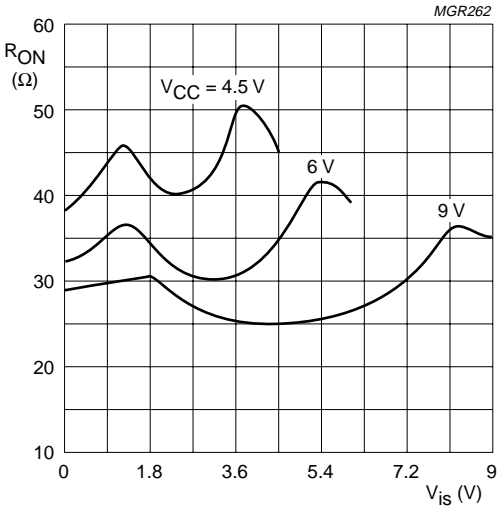


Fig.9 Typical ON-resistance ( $R_{ON}$ ) as a function of input voltage ( $V_{is}$ ) for  $V_{is} = 0$  to  $V_{CC}$ .



## Quad bilateral switches

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## DC CHARACTERISTICS FOR 74HC

Voltage are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)							UNIT	TEST CONDITIONS		
		74HC								V <sub>CC</sub> (V)	V <sub>I</sub>	OTHER
		+25			−40 to +85		−40 to +125					
		min.	typ.	max.	min.	max.	min.	max.				
V <sub>IH</sub>	HIGH-level input voltage	1.5	1.2		1.5		1.5		V	2.0		
		3.15	2.4		3.15		3.15			4.5		
		4.2	3.2		4.2		4.2			6.0		
		6.3	4.7		6.3		6.3			9.0		
V <sub>IL</sub>	LOW-level input voltage		0.8	0.50		0.50		0.50	V	2.0		
			2.1	1.35		1.35		1.35		4.5		
			2.8	1.80		1.80		1.80		6.0		
			4.3	2.70		2.70		2.70		9.0		
±I <sub>I</sub>	input leakage current			0.1 0.2		1.0 2.0		1.0 2.0	μA	6.0 10.0	V <sub>CC</sub> or GND	
±I <sub>S</sub>	analog switch OFF-state current per channel			0.1		1.0		1.0	μA	10.0	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub> = V <sub>CC</sub> − GND (see Fig.7)
±I <sub>S</sub>	analog switch ON-state current			0.1		1.0		1.0	μA	10.0	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub> = V <sub>CC</sub> − GND (see Fig.8)
I <sub>CC</sub>	quiescent supply current			2.0 4.0		20.0 40.0		40.0 80.0	μA	6.0 10.0	V <sub>CC</sub> or GND	V <sub>IS</sub> = GND or V <sub>CC</sub> ; V <sub>OS</sub> = V <sub>CC</sub> or GND

## Quad bilateral switches

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## AC CHARACTERISTICS FOR 74HC

GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)							UNIT	TEST CONDITIONS	
		74HC								V <sub>CC</sub> (V)	OTHER
		+25			−40 to +85		−40 to +125				
		min.	typ.	max.	min.	max.	min.	max.			
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay V <sub>is</sub> to V <sub>os</sub>		8 3 2 2	60 12 10 8		75 15 13 10		90 18 15 12	ns	2.0 4.5 6.0 9.0	R <sub>L</sub> = ∞; C <sub>L</sub> = 50 pF (see Fig.18)
t <sub>PZH</sub> /t <sub>PZL</sub>	turn-on time nE to V <sub>os</sub>		36 13 10 8	100 20 17 13		125 25 21 16		150 30 26 20	ns	2.0 4.5 6.0 9.0	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 19 and 20)
t <sub>PHZ</sub> /t <sub>PLZ</sub>	turn-off time nE to V <sub>os</sub>		44 16 13 16	150 30 26 24		190 38 33 16		225 45 38 20	ns	2.0 4.5 6.0 9.0	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 19 and 20)

## Quad bilateral switches

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**DC CHARACTERISTICS FOR 74HCT**

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)							UNIT	TEST CONDITIONS		
		74HCT								V <sub>CC</sub> (V)	V <sub>I</sub>	OTHER
		+25			−40 to +85		−40 to +125					
		min.	typ.	max.	min.	max.	min.	max.				
V <sub>IH</sub>	HIGH-level input voltage	2.0	1.6		2.0		2.0		V	4.5 to 5.5		
V <sub>IL</sub>	LOW-level input voltage		1.2	0.8		0.8		0.8	V	4.5 to 5.5		
±I <sub>I</sub>	input leakage current			0.1		1.0		1.0	μA	5.5	V <sub>CC</sub> or GND	
±I <sub>S</sub>	analog switch OFF-state current per channel			0.1		1.0		1.0	μA	5.5	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub> = V <sub>CC</sub> − GND (see Fig.7)
±I <sub>S</sub>	analog switch ON-state current			0.1		1.0		1.0	μA	5.5	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub> = V <sub>CC</sub> − GND (see Fig.8)
I <sub>CC</sub>	quiescent supply current			2.0		20.0		40.0	μA	4.5 to 5.5	V <sub>CC</sub> or GND	V <sub>is</sub> = GND or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or GND
ΔI <sub>CC</sub>	additional quiescent supply current per input pin for unit load coefficient is 1 (note 1)		100	360		450		490	μA	4.5 to 5.5	V <sub>CC</sub> − 2.1 V	other inputs at V <sub>CC</sub> or GND

**Note**

- The value of additional quiescent supply current ( $\Delta I_{CC}$ ) for a unit load of 1 is given here. To determine  $\Delta I_{CC}$  per input, multiply this value by the unit load coefficient shown in the table below.

**Table 1**

INPUT	UNIT LOAD COEFFICIENT
nE	1.00

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## AC CHARACTERISTICS FOR 74HCT

GND = 0 V;  $t_r = t_f = 6$  ns

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)								UNIT	TEST CONDITIONS	
		74HCT									V <sub>CC</sub> (V)	OTHER
		+25			−40 to +85		−40 to +125					
		min.	typ.	max.	min.	max.	min.	max.				
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay V <sub>is</sub> to V <sub>os</sub>		3	12		15		18	ns	4.5	R <sub>L</sub> = ∞; C <sub>L</sub> = 50 pF (see Fig.18)	
t <sub>PZH</sub> /t <sub>PZL</sub>	turn-on time nE to V <sub>os</sub>		12	24		30		36	ns	4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 19 and 20)	
t <sub>PHZ</sub> /t <sub>PLZ</sub>	turn-off time nE to V <sub>os</sub>		20	35		44		53	ns	4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 19 and 20)	

## ADDITIONAL AC CHARACTERISTICS FOR 74HC/HCT

Recommended conditions and typical values GND = 0 V;  $t_r = t_f = 6$  ns

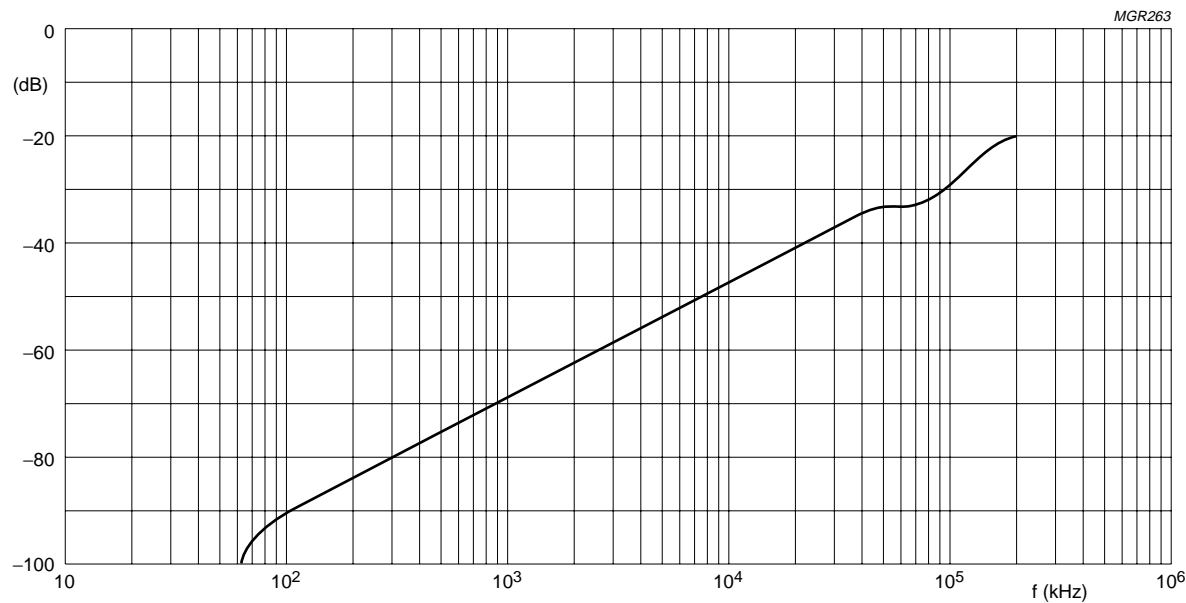
SYMBOL	PARAMETER	TYP.	UNIT	$V_{CC}$ (V)	$V_{IS(p-p)}$ (V)	CONDITIONS
	sine wave distortion $f = 1$ kHz	0.04 0.02	% %	4.5 9.0	4.0 8.0	$R_L = 10$ k $\Omega$ ; $C_L = 50$ pF (see Fig.16)
	sine wave distortion $f = 10$ kHz	0.12 0.06	% %	4.5 9.0	4.0 8.0	$R_L = 10$ k $\Omega$ ; $C_L = 50$ pF (see Fig.16)
	switch "OFF" signal feed-through	−50 −50	dB dB	4.5 9.0	note 3	$R_L = 600$ $\Omega$ ; $C_L = 50$ pF; $f = 1$ MHz (see Figs 10 and 17)
	crosstalk between any two switches	−60 −60	dB dB	4.5 9.0	note 3	$R_L = 600$ $\Omega$ ; $C_L = 50$ pF; $f = 1$ MHz (see Fig.12)
$V_{(p-p)}$	crosstalk voltage between enable or address input to any switch (peak-to-peak value)	110 220	mV mV	4.5 9.0		$R_L = 600$ $\Omega$ ; $C_L = 50$ pF; $f = 1$ MHz (nE, square wave between $V_{CC}$ and GND, $t_r = t_f = 6$ ns) (see Fig.14)
$f_{max}$	minimum frequency response (−3 dB)	180 200	MHz MHz	4.5 9.0	note 4	$R_L = 50$ $\Omega$ ; $C_L = 10$ pF (see Figs 11 and 15)
$C_S$	maximum switch capacitance	8	pF			

## Notes

1.  $V_{IS}$  is the input voltage at nY or nZ terminal, whichever is assigned as an input.
2.  $V_{OS}$  is the output voltage at nY or nZ terminal, whichever is assigned as an output.
3. Adjust input voltage  $V_{IS}$  is 0 dBm level (0 dBm = 1 mW into 600  $\Omega$ ).
4. Adjust input voltage  $V_{IS}$  is 0 dBm level at  $V_{OS}$  for 1 MHz (0 dBm = 1 mW into 50  $\Omega$ ).

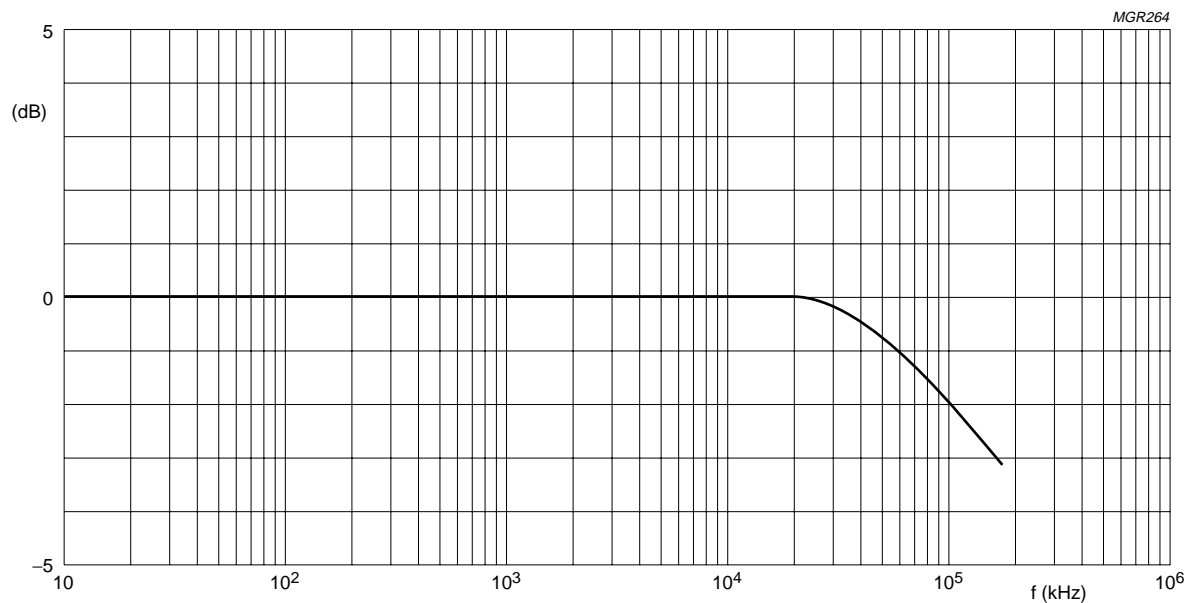
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Test conditions:  $V_{CC} = 4.5\text{ V}$ ;  $GND = 0\text{ V}$ ;  $R_L = 50\text{ }\Omega$ ;  $R_{source} = 1\text{ k}\Omega$ .

Fig.10 Typical switch "OFF" signal feed-through as a function of frequency.



Test conditions:  $V_{CC} = 4.5\text{ V}$ ;  $GND = 0\text{ V}$ ;  $R_L = 50\text{ }\Omega$ ;  $R_{source} = 1\text{ k}\Omega$ .

Fig.11 Typical frequency response.

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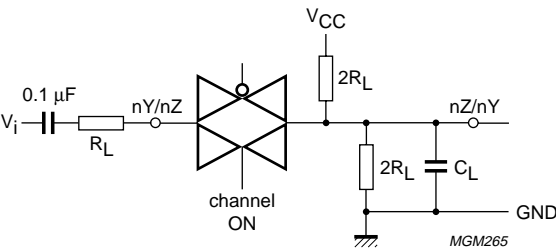


Fig.12 Test circuit for measuring crosstalk between any two switches; channel ON condition.

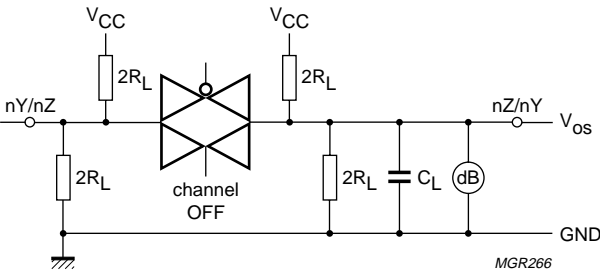


Fig.13 Test circuit for measuring crosstalk between any two switches; channel OFF condition.

The crosstalk is defined as follows (oscilloscope output):

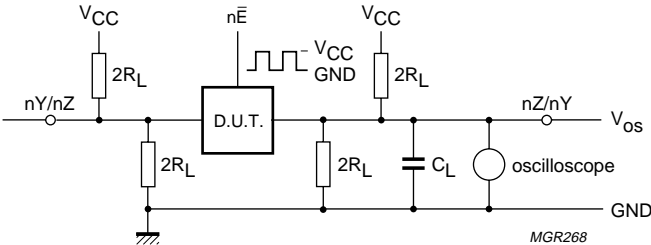
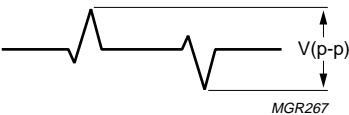
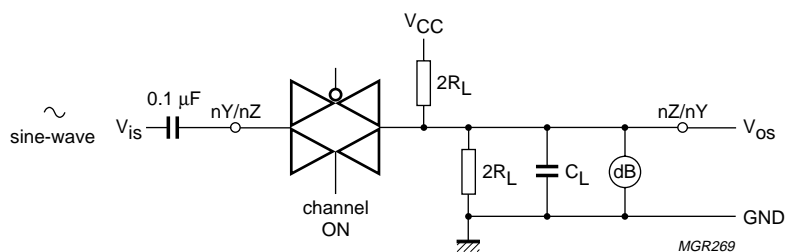


Fig.14 Test circuit for measuring crosstalk between control and any switch.

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Adjust input voltage to obtain 0 dBm at  $V_{os}$  when  $f_{in} = 1$  MHz. After set-up frequency of  $f_{in}$  is increased to obtain a reading of -3 dB at  $V_{os}$ .

Fig.15 Test circuit for measuring minimum frequency response.

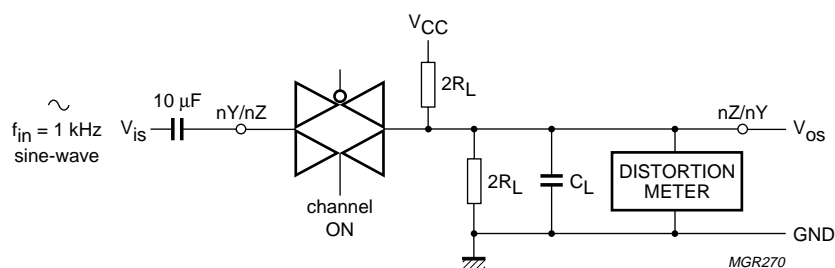


Fig.16 Test circuit for measuring sine wave distortion.

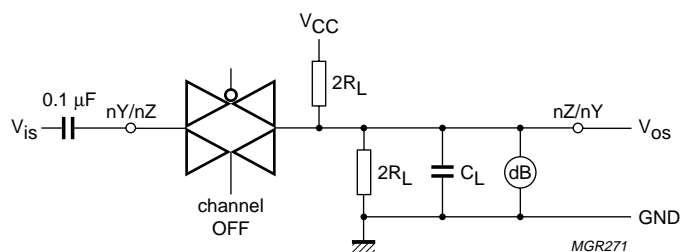
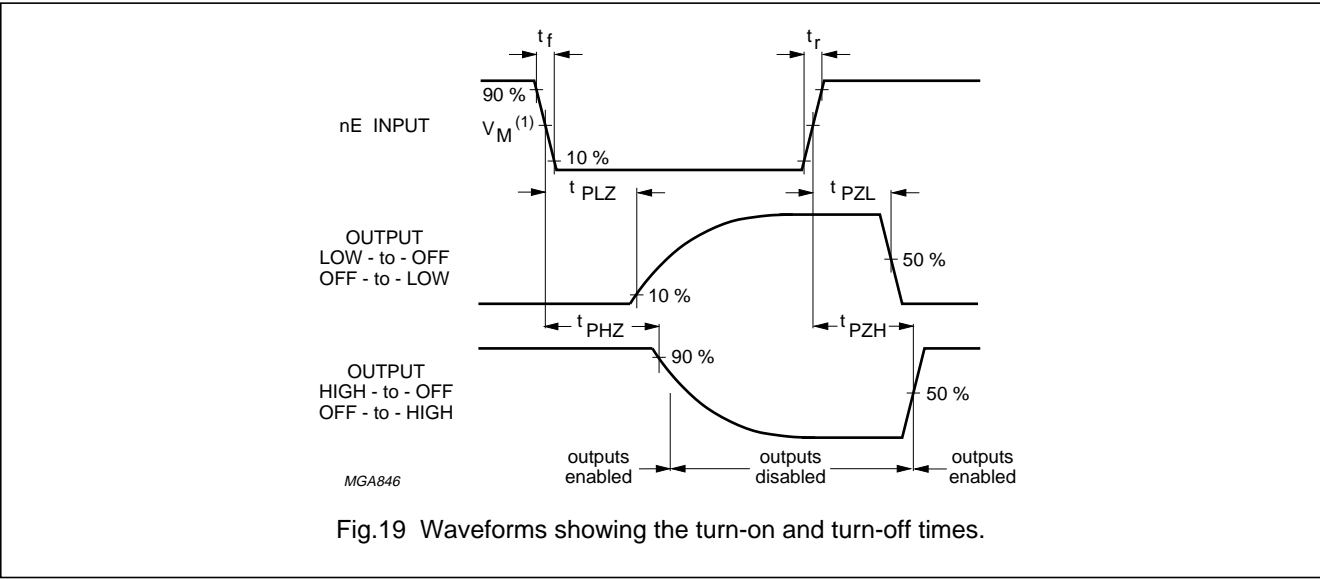
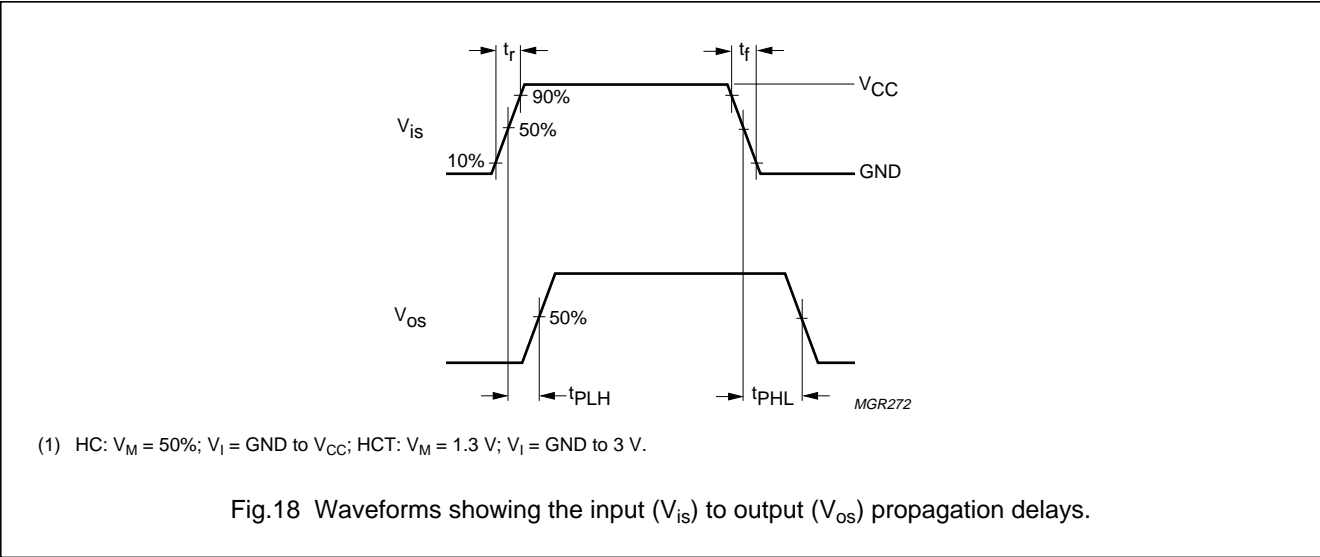


Fig.17 Test circuit for measuring switch "OFF" signal feed-through.

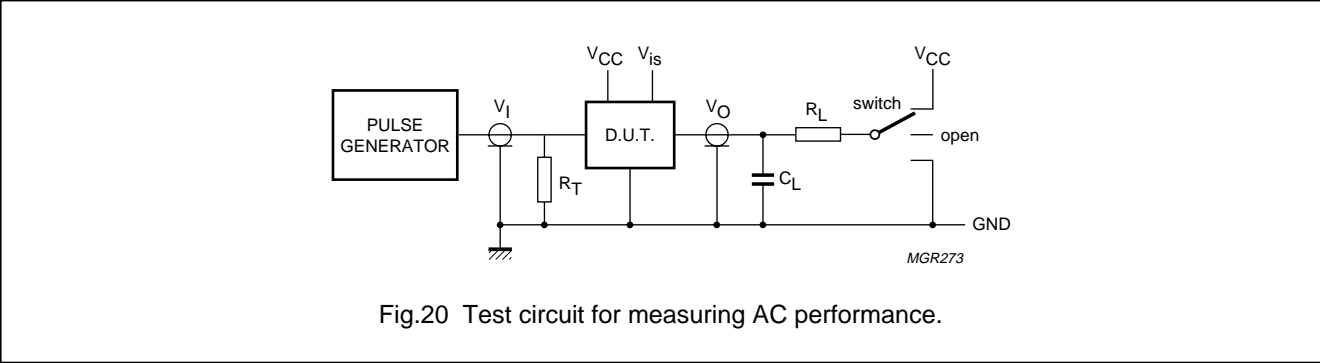
Quad bilateral switches

74HC/HCT4066

AC WAVEFORMS



TEST CIRCUIT AND WAVEFORMS





Quad bilateral switches

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Table 2 Conditions

TEST	SWITCH	V <sub>IS</sub>
t <sub>PZH</sub>	GND	V <sub>CC</sub>
t <sub>PZL</sub>	V <sub>CC</sub>	GND
t <sub>PHZ</sub>	GND	V <sub>CC</sub>
t <sub>PLZ</sub>	V <sub>CC</sub>	GND
others	open	pulse

Table 3 Definitions for Figs 20 and 21:

SYMBOL	DEFINITION
C <sub>L</sub>	load capacitance including jig and probe capacitance (see AC CHARACTERISTICS for values)
R <sub>T</sub>	termination resistance should be equal to the output impedance Z <sub>O</sub> of the pulse generator
t <sub>r</sub>	t <sub>f</sub> = 6 ns, when measuring f <sub>max</sub> , there is no constraint on t <sub>r</sub> , t <sub>f</sub> with 50% duty factor

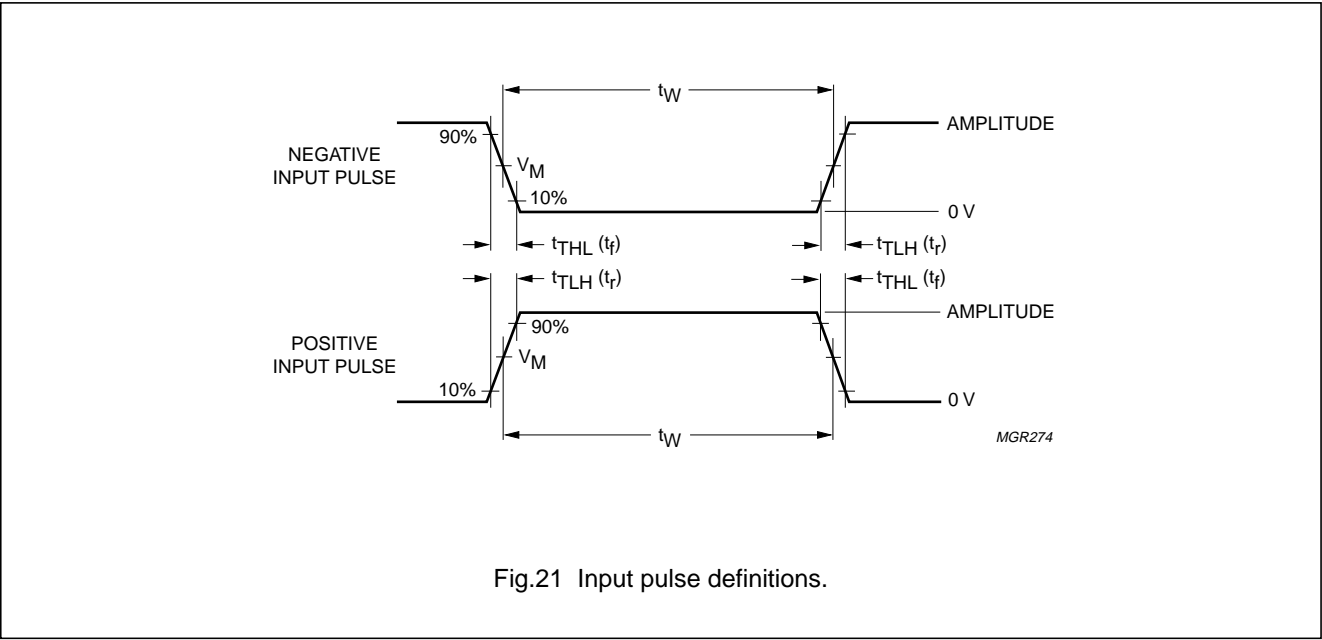


Table 4

FAMILY	AMPLITUDE	V <sub>M</sub>	t <sub>r</sub> ; t <sub>f</sub>	
			f <sub>max</sub> ; PULSE WIDTH	OTHER
74HC	V <sub>CC</sub>	50%	< 2 ns	6 ns
74HCT	3.0 V	1.3 V	< 2 ns	6 ns

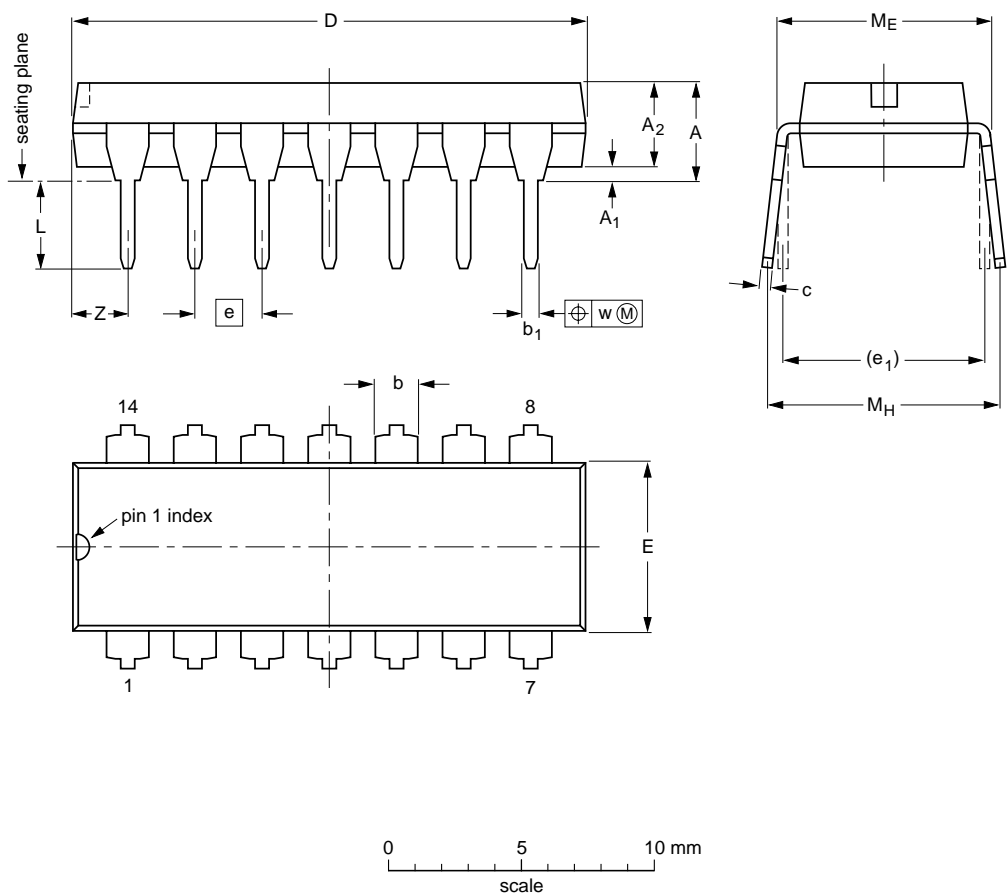
Quad bilateral switches

74HC/HCT4066

PACKAGE OUTLINES

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1




DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	c	D <sup>(1)</sup>	E <sup>(1)</sup>	e	e <sub>1</sub>	L	M <sub>E</sub>	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

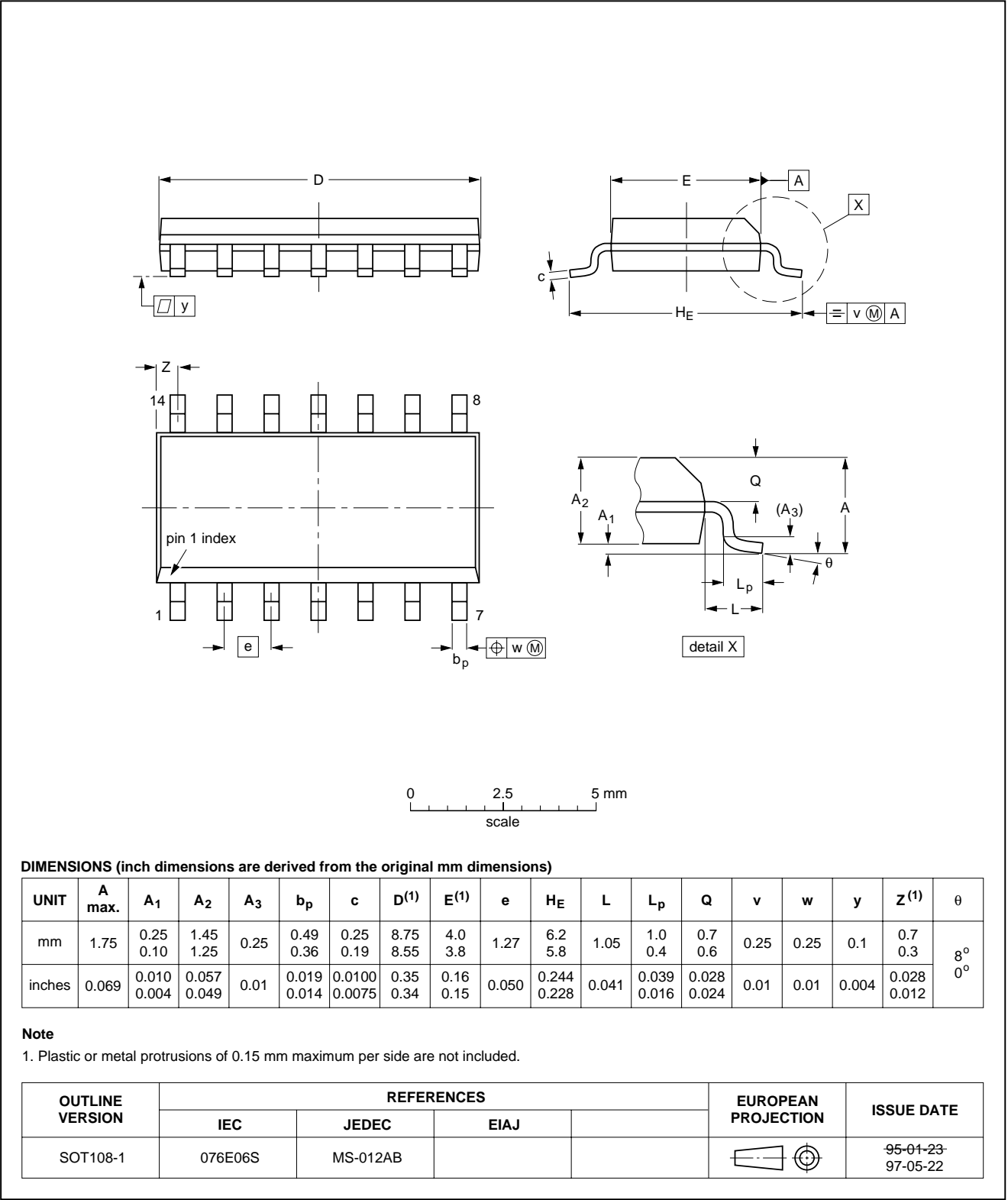
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT27-1	050G04	MO-001AA				92-11-17 95-03-11

Quad bilateral switches

74HC/HCT4066

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1

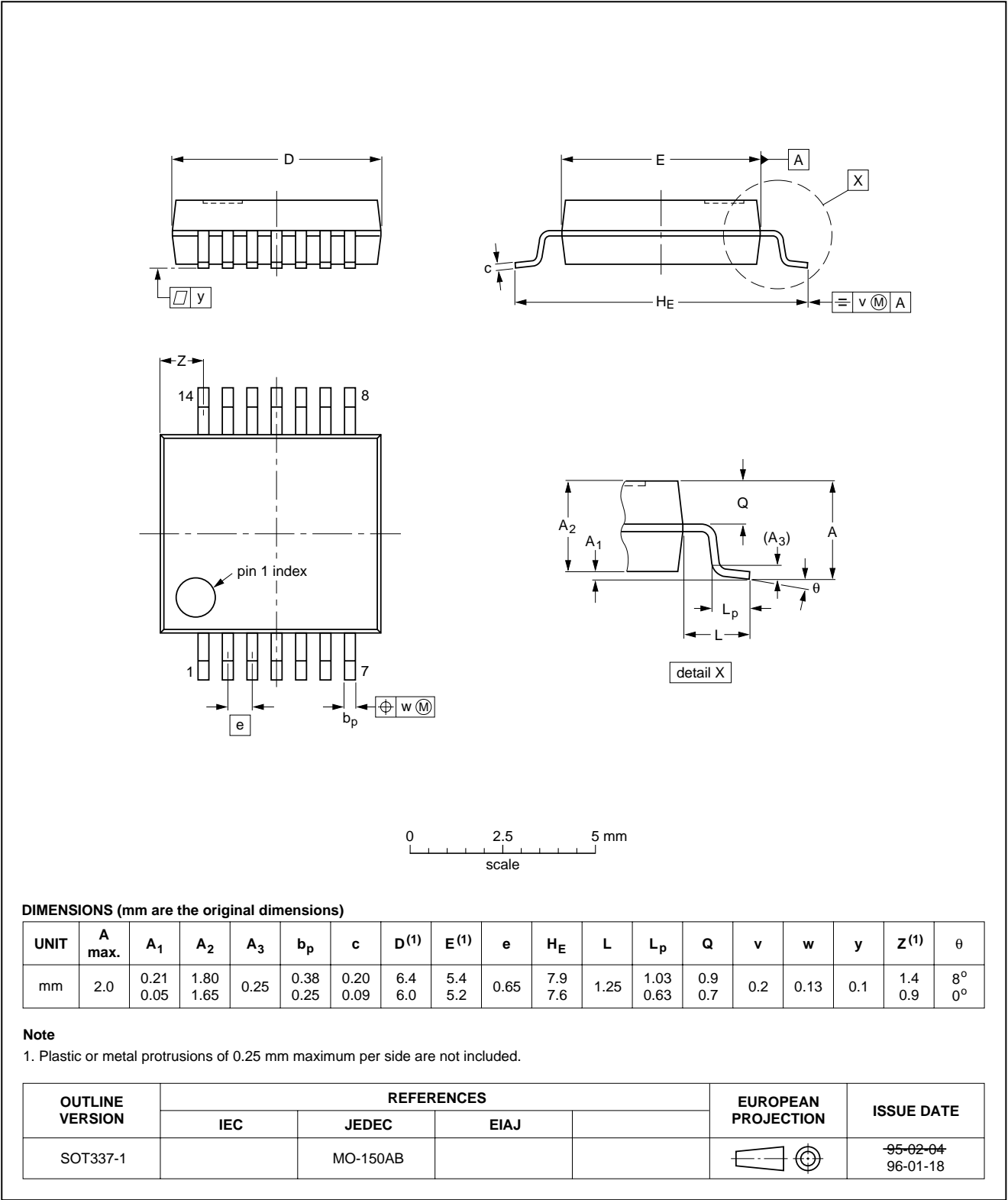


Quad bilateral switches

74HC/HCT4066

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1

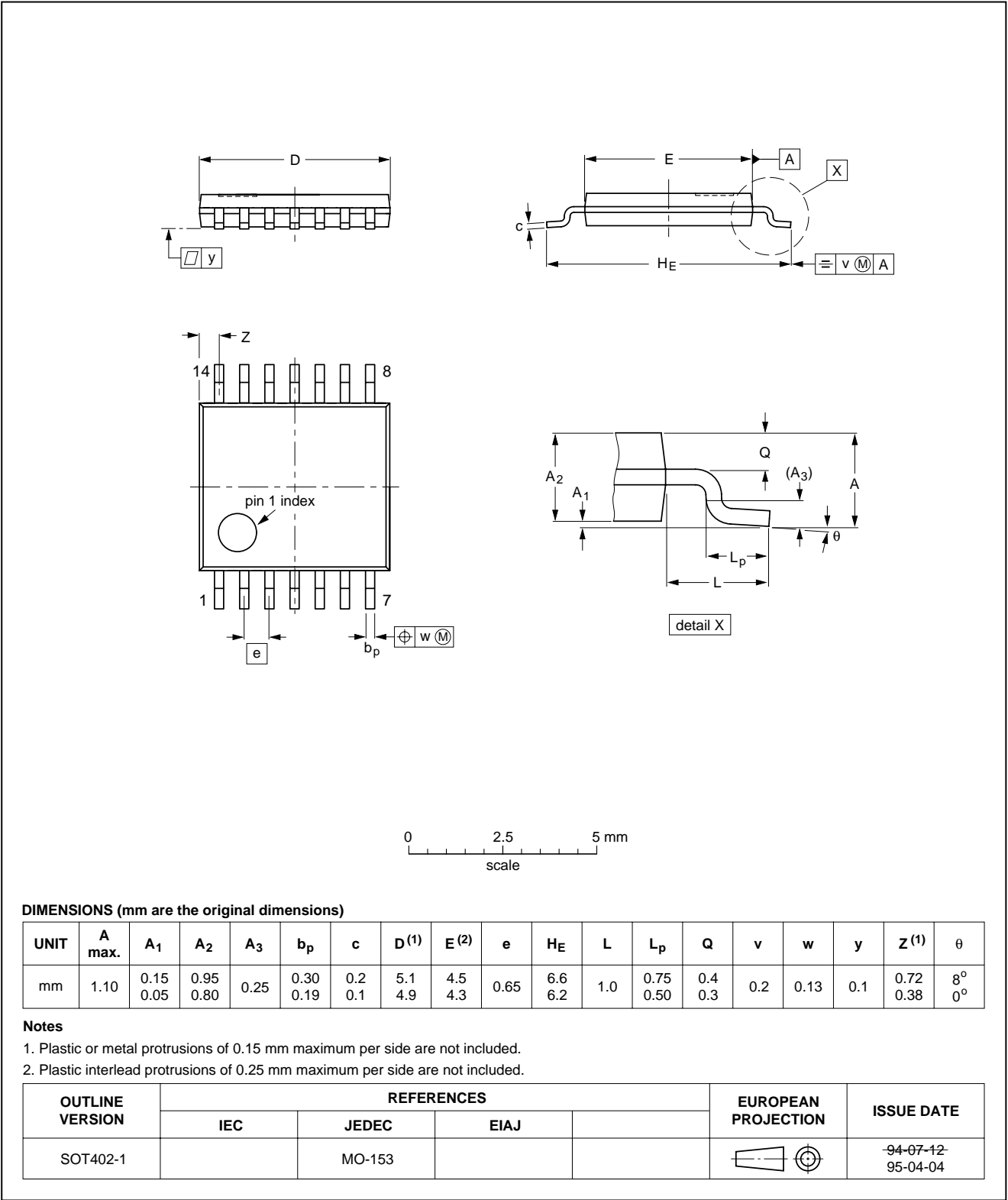


Quad bilateral switches

74HC/HCT4066

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



## Quad bilateral switches

## 74HC/HCT4066

### SOLDERING

#### Introduction

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (document order number 9398 652 90011).

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mount components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mount ICs, or for printed-circuit boards with high population densities. In these situations reflow soldering is often used.

#### Through-hole mount packages

##### SOLDERING BY DIPPING OR BY SOLDER WAVE

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact with the joints for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ( $T_{stg(max)}$ ). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

##### MANUAL SOLDERING

Apply the soldering iron (24 V or less) to the lead(s) of the package, either below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than 300 °C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 °C, contact may be up to 5 seconds.

#### Surface mount packages

##### REFLOW SOLDERING

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, infrared/convection heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferably be kept below 230 °C.

##### WAVE SOLDERING

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
  - larger than or equal to 1.27 mm, the footprint longitudinal axis is **preferred** to be parallel to the transport direction of the printed-circuit board;
  - smaller than 1.27 mm, the footprint longitudinal axis **must** be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

- For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

##### MANUAL SOLDERING

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

## Quad bilateral switches

## 74HC/HCT4066

## Suitability of IC packages for wave, reflow and dipping soldering methods

MOUNTING	PACKAGE	SOLDERING METHOD		
		WAVE	REFLOW <sup>(1)</sup>	DIPPING
Through-hole mount	DBS, DIP, HDIP, SDIP, SIL	suitable <sup>(2)</sup>	–	suitable
Surface mount	HLQFP, HSQFP, HSOP, SMS	not suitable <sup>(3)</sup>	suitable	–
	PLCC <sup>(4)</sup> , SO	suitable	suitable	–
	LQFP, QFP, TQFP	not recommended <sup>(4)(5)</sup>	suitable	–
	SQFP	not suitable	suitable	–
	SSOP, TSSOP, VSO	not recommended <sup>(6)</sup>	suitable	–

## Notes

1. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the *"Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods"*.
2. For SDIP packages, the longitudinal axis must be parallel to the transport direction of the printed-circuit board.
3. These packages are not suitable for wave soldering as a solder joint between the printed-circuit board and heatsink (at bottom version) can not be achieved, and as solder may stick to the heatsink (on top version).
4. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
5. Wave soldering is only suitable for LQFP, QFP and TQFP packages with a pitch (e) equal to or larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
6. Wave soldering is only suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

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Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
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